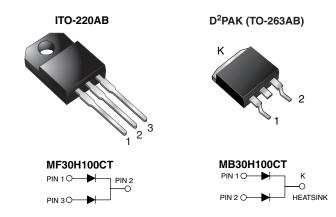


Vishay General Semiconductor

HALOGEN FREE

Dual Common Cathode High Voltage Schottky Rectifier

High Barrier Technology for Improved High Temperature Performance



PRIMARY CHARACTERISTICS					
I _{F(AV)}	2 x 15 A				
V _{RRM}	100 V				
I _{FSM}	275 A				
V _F	0.67 V				
I _R	5.0 μA				
T _J max.	175 °C				
Package	ITO-220AB, D ² PAK (TO-263AB)				
Circuit configuration	Common cathode				

FEATURES

- Power pack
- · Guardring for overvoltage protection
- · Low power loss, high efficiency
- Low forward voltage drop
- · Low leakage current
- High forward surge capability
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for D²PAK (TO-263AB) package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for ITO-220AB package)
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters, and polarity protection application.

MECHANICAL DATA

Case: ITO-220AB, D2PAK (TO-263AB)

Molding compound meets UL 94 V-0 flammability rating

Base P/NHE3_X - RoHS-compliant, AEC-Q101 qualified ("_X" denotes revision code e.g. A, B,.....)

Base P/NHM3 - RoHS-compliant, halogen-free, AEC-Q101 qualified

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

HE3 and HM3 suffix meets JESD 201 class 2 whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

PARAMETER		SYMBOL	MB30H100CT	MF30H100CT	UNIT	
Maximum repetitive peak reverse voltage		V_{RRM}	100			
Working peak reverse voltage		V_{RWM}	100		V	
Maximum DC blocking voltage		V_{DC}	100			
Maximum average forward rectified current	total device	I	30		-	
(fig.1)	per diode	I _{F(AV)}	15			
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I _{FSM}	275		А	
Peak repetitive reverse surge current per diode at t	_o = 2.0 μs, 1 kHz	I _{RRM}	1.0			
Voltage rate of change (rated V _R)		dV/dt	10 000		V/µs	
Operating junction and storage temperature range		T _J , T _{STG}	-65 to +175		°C	
Isolation voltage (ITO-220AB only) from terminal to heat sink t = 1 min		V _{AC}	15	000	V	



MB30H100CT, MF30H100CT

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ELECTRICAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUE	UNIT	
Maximum instantaneous forward voltage per diode	V _F (1)	I _F = 15 A	T _J = 25 °C	0.82	- V	
		I _F = 15 A	T _J = 125 °C	0.67		
		I _F = 30 A	T _J = 25 °C	0.93		
		I _F = 30 A	T _J = 125 °C	0.80		
Maximum reverse current per diode	I _R ⁽²⁾	Rated V _R	T _J = 25 °C	5.0	μΑ	
			T _J = 125 °C	6.0	mA	

Note

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width, ≤ 40 ms

THERMAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	MB30H100CT	MF30H100CT	UNIT		
Typical thermal resistance per diode	$R_{ heta JC}$	1.9	4.6	°C/W		

ORDERING INFORMATION							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
ITO-220AB	MF30H100CTHE3_B/P	1.99	Р	50/tube	Tube		
D ² PAK (TO-263AB)	MB30H100CTHM3/I	1.35	I	800/reel	Tape and reel		

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RATINGS AND CHARACTERISTICS CURVES (T_C = 25 °C unless otherwise noted)

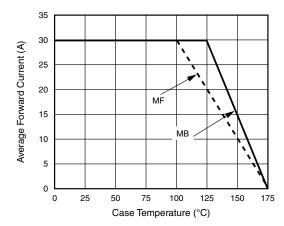


Fig. 1 - Forward Derating Curve Per Diode

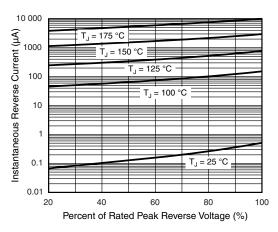


Fig. 4 - Typical Reverse Characteristics Per Diode

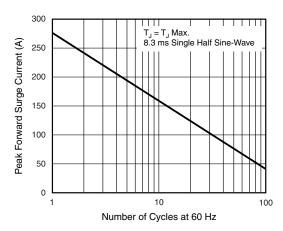


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

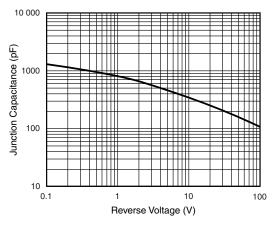


Fig. 5 - Typical Junction Capacitance Per Diode

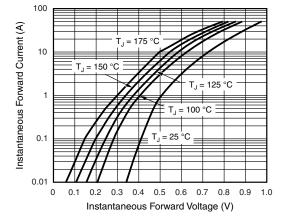


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

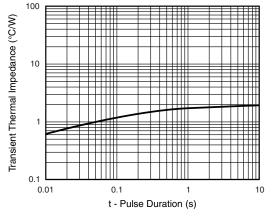
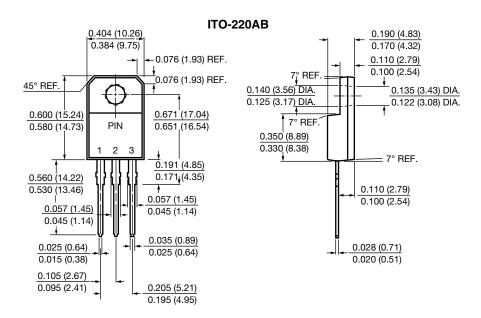


Fig. 6 - Typical Transient Thermal Impedance Per Diode



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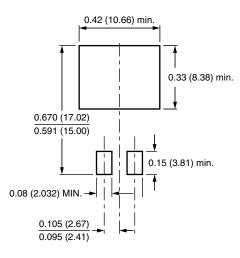
PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



D²PAK (TO-263AB)

0.190 (4.83) 0.411 (10.45) 0.380 (9.65) 0.160 (4.06) 0.055 (1.40) 0.045 (1.14) 0.245 (6.22) MIN. 0.055 (1.40) 0.360 (9.14) 0.047 (1.19) 0.320 (8.13) 0.624 (15.85) Κ 2 0.591 (15.00) -0 to 0.01 (0 to 0.254) 0.110 (2.79) <u>†</u> 0.090 (2.29) 0.037 (0.940) 0.021 (0.53) 0.027 (0.686) 0.014 (0.36) 0.105 (2.67) 0.140 (3.56) 0.095 (2.41) 0.205 (5.20) 0.110 (2.79) 0.195 (4.95)

Mounting Pad Layout





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